

Supporting Information

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Tuning ZnO Sensors Reactivity Towards Volatile Organic Compounds

via Ag Doping and Nanoparticle Functionalisation

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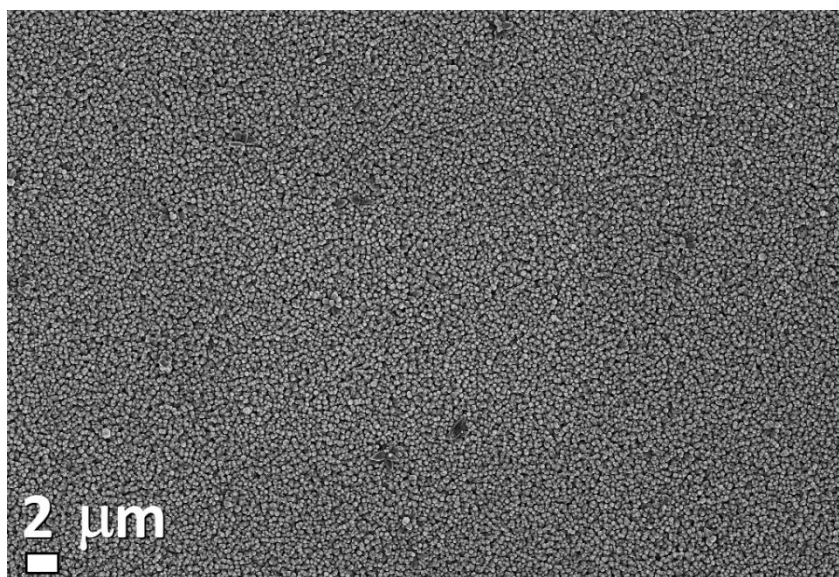


Figure S1. SEM image of ZnO:Ag (0.5 wt%) films treated with RTA at 575 °C for 60 s.

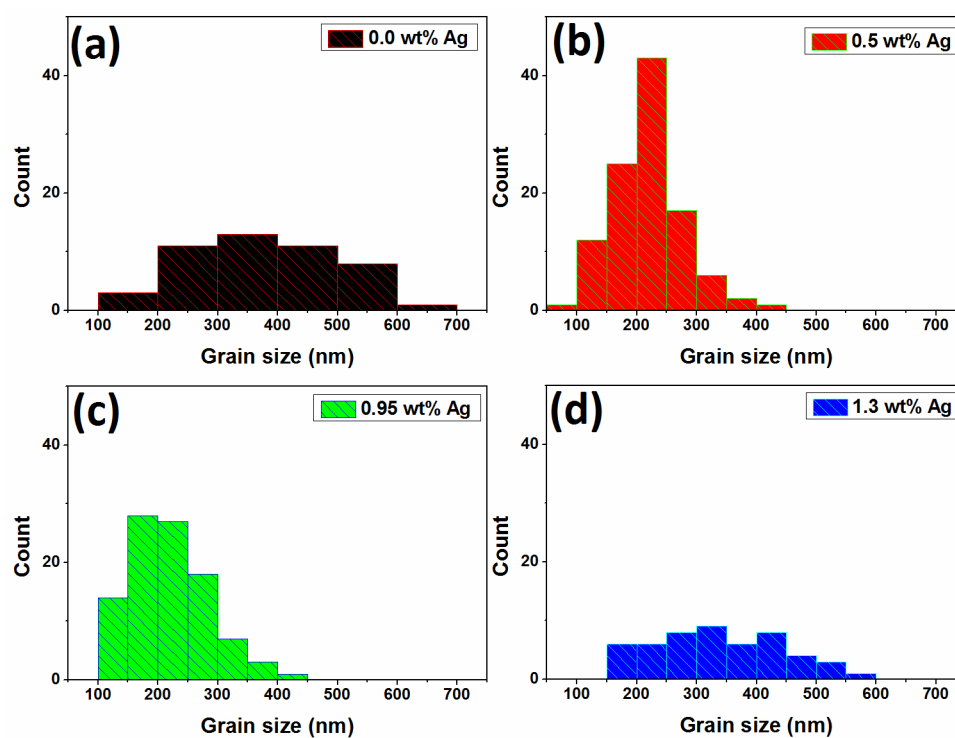


Figure S2. Column size histogram of ZnO:Ag columnar films with: (a) 0.00; (b) 0.50; (c) 0.95; and (d) 1.3 wt% Ag.

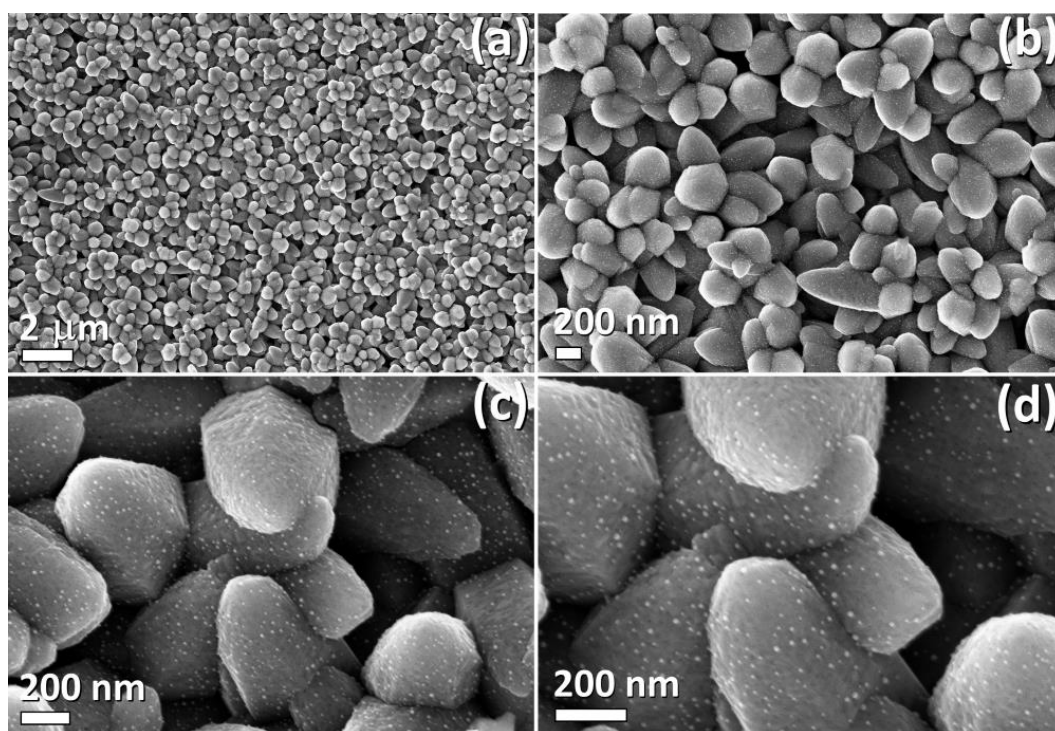


Figure S3. SEM images of Ag/ZnO:Ag columnar films at different magnifications from:
(a,b) lower; to (c,d) higher.

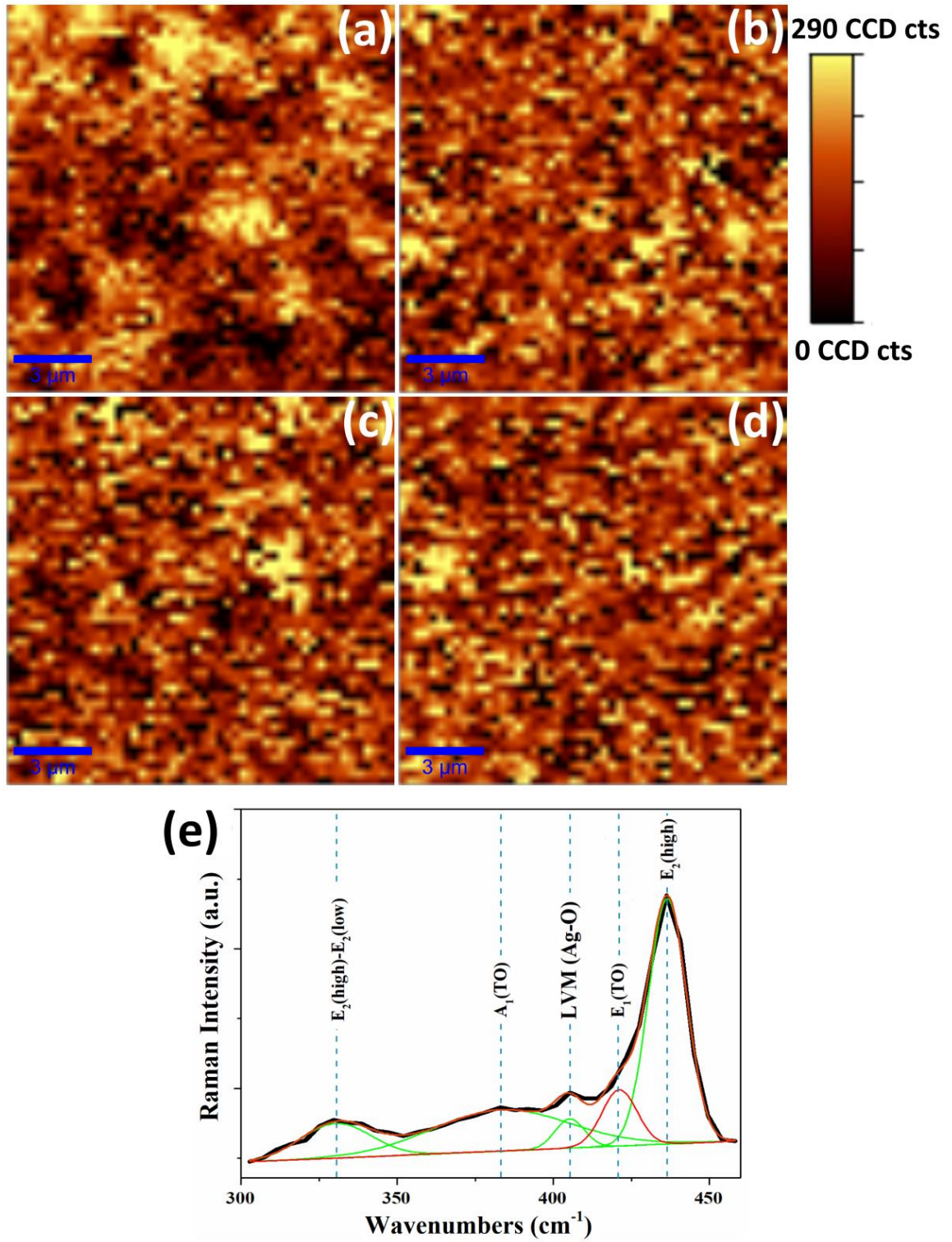


Figure S4. Raman mapping for the $E_2(\text{high})$ band (integrated between 420 and 450 cm^{-1}) of the ZnO:Ag columnar films treated with RTA at 575 °C for 60 s with: (a) 0.0; (b) 0.5; (c) 0.95; and (d) 1.3 wt% Ag. (e) Deconvolution of the 300-460 cm^{-1} region using a Gaussian fit for the sample with 1.3 wt% Ag.

Figure S4e shows the deconvolution using a Gaussian fitting of the 300-460 cm⁻¹ Raman spectroscopy range for the sample with 1.3 wt% Ag (see **Figure S4e**). For the samples with 1.3 wt% Ag, the additional local vibrational modes (LVM) at 402 cm⁻¹ and 235 cm⁻¹ arise due to the intrinsic host lattice defects induced by the Ag atoms located in the O sites (Ag_O) and Zn sites (Ag_{Zn}), respectively, in agreement with XRD experiments.¹⁻⁴ The intensity of the LVM increases with the Ag content, which has also been reported in literature for Ag-doped ZnO films.^{5,6} A plausible mechanism to account for the origin of the LVM peak comprises Ag impurity centers breaking the translational symmetry of the ZnO crystal which relaxes the conservation of the wave vectors, allowing them far from the dopant center.^{3,6}

Equation (S1) gives the estimated Ag-related LVM frequency from the effective masses [$\mu = (1/M + 1/m)^{-1}$] of the ZnO and LVM:^{6,7}

$$\frac{\omega(LVM)}{\omega(ZnO)} = \sqrt{\frac{\mu_{ZnO}}{\mu_{LVM}}} \quad (S1)$$

From $\omega(ZnO) = \omega[E_2(\text{high})] = 436 \text{ cm}^{-1}$ we obtained the value of 245 cm⁻¹ for Ag_O (LVM of Zn-Ag). The calculated frequency of the LVM for the Ag-Zn pair is consistent with the experimental value of 235 cm⁻¹, confirming that this signal is induced by the Ag atoms located in the Zn sites of the ZnO lattice.^{6,7} In the same way, the mode at 402 cm⁻¹ is the LVM induced by the Ag atoms located in the O sites of the ZnO lattice.^{6,7} **Figure S4e**, shows that the relative intensity of the LVM peaks for Zn-Ag is higher than for Ag-O, strongly suggesting that Ag mainly replace Zn atoms.^{6,7,8}

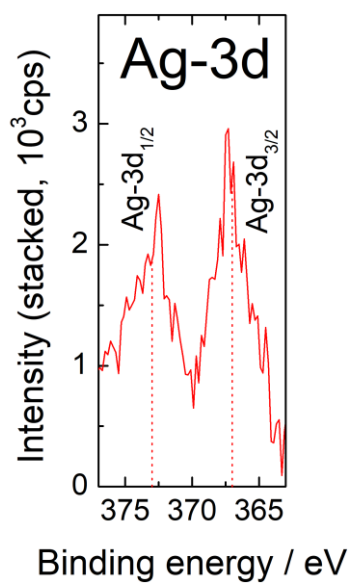


Figure S5. XPS plot of the Ag-3d lines of a ZnO:Ag reference layer with increased (10-fold) Ag doping concentration (123 mM of AgNO₃).

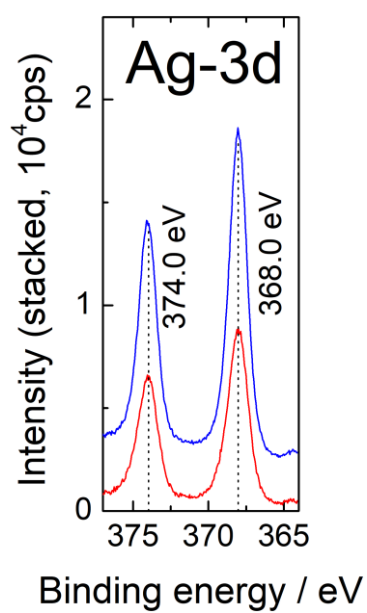


Figure S6. XPS plot of the Ag-3d lines of a ZnO:Ag films with Ag nanoclusters as-grown (red line) and annealed ones at 300 °C for 1 h (blue line).

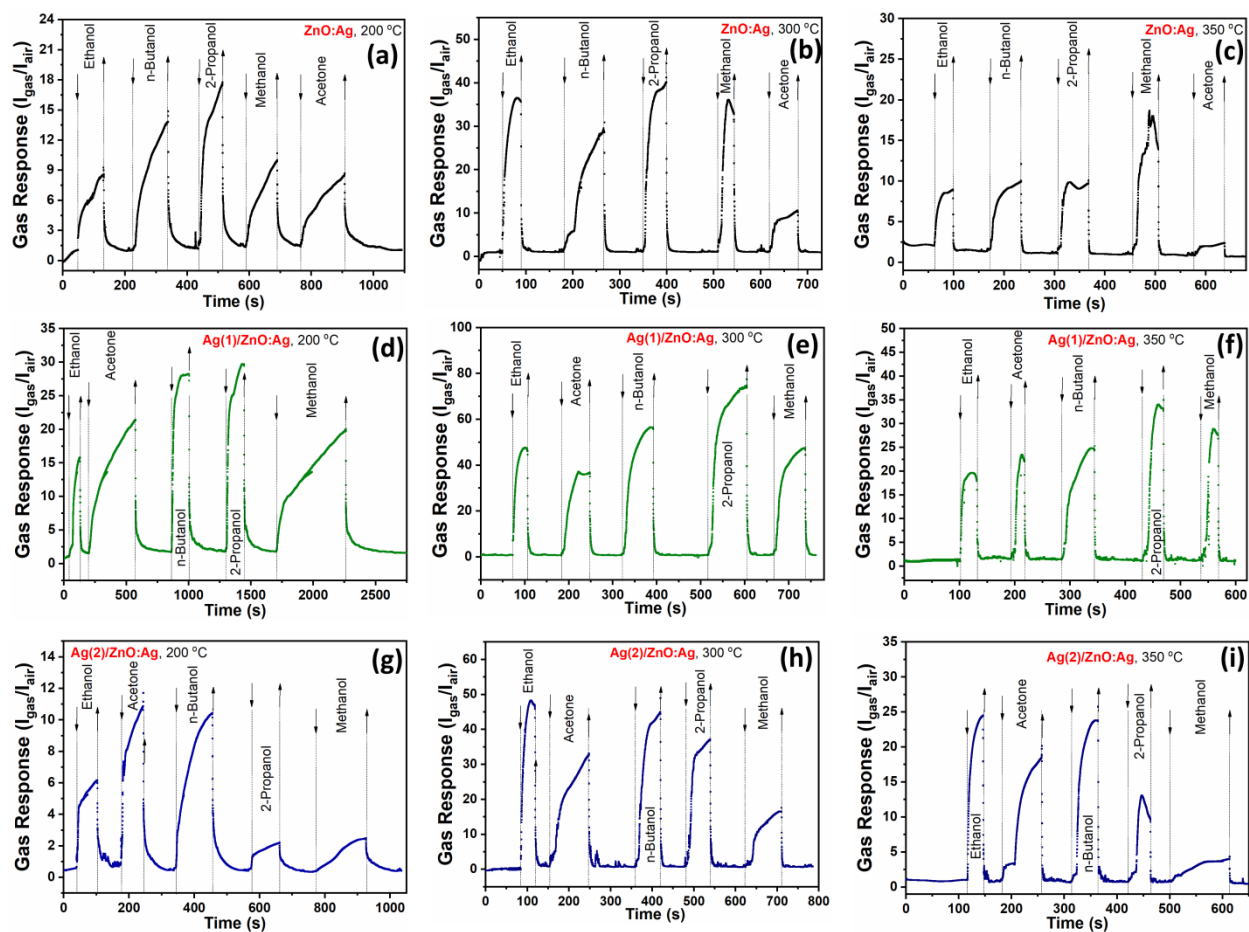


Figure S7. Dynamic response to 100 ppm of VOC vapors for: ZnO:Ag films based sensor structures at: (a) 200 °C, (b) 300 °C and (c) 350 °C; Ag(1)/ZnO:Ag at: (d) 200 °C, (e) 300 °C and (f) 350 °C, and Ag(2)/ZnO:Ag at: (g) 200 °C, (h) 300 °C and (i) 350 °C.

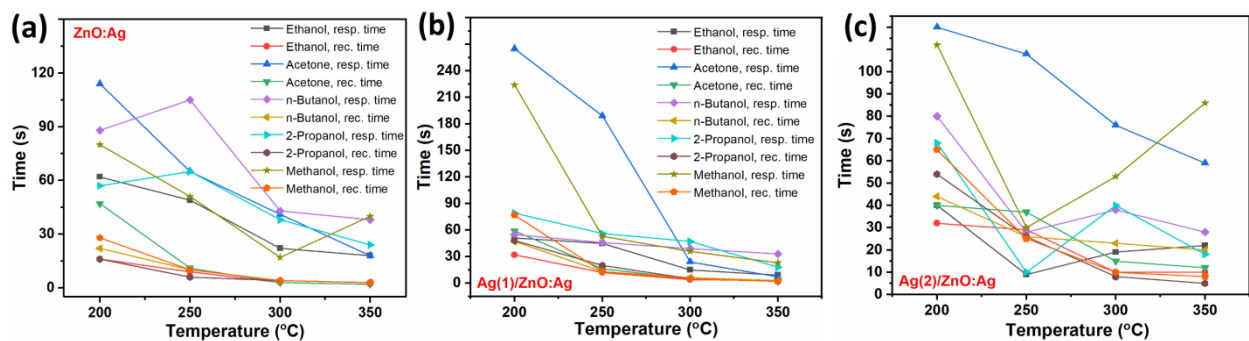


Figure S8. Calculated response (resp.) and recovery times (rec.) as a function of temperature for: (a) ZnO:Ag, (b) Ag(1)/ZnO:Ag and (c) Ag(2)/ZnO:Ag columnar films based sensor structures.

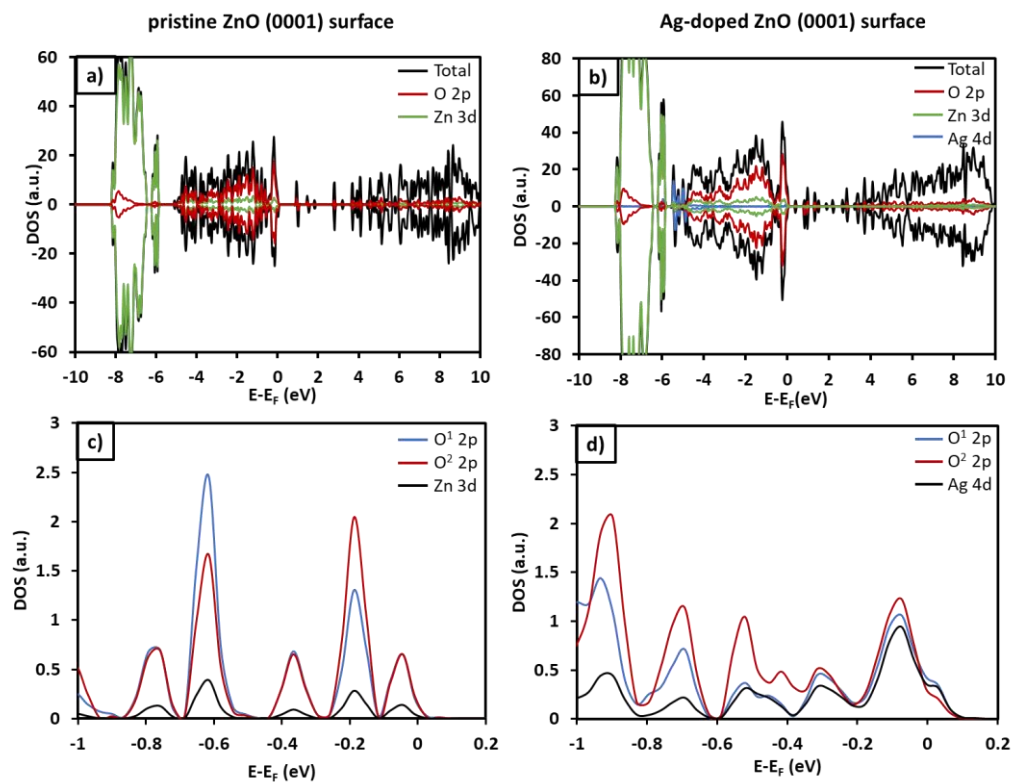


Figure S9. (a and b) Electronic density of states (DOS) of the pristine and Ag-doped ZnO(0001) surfaces, respectively. (c and d) Atomic projected DOS of the pristine and Ag-doped ZnO(0001) surfaces, respectively.

Table S1. Calculated response and recovery times to VOCs vapors at different operating temperatures for columnar films based sensor structures.

Sample	VOCs	Time	Temperature, ° C			
			200	250	300	350
ZnO:Ag	Ethanol	Resp. time (s)	62	49	22	18
		Rec. time (s)	16	9	3	2
	Acetone	Resp. time (s)	114	65	41	18
		Rec. time (s)	47	11	3	2
	<i>n</i> -Butanol	Resp. time (s)	88	105	43	38
		Rec. time (s)	22	10	4	3
	2-Propanol	Resp. time (s)	57	65	38	24
		Rec. time (s)	16	6	4	3
	Methanol	Resp. time (s)	80	51	17	40
		Rec. time (s)	28	10	4	3
Ag(1)/ZnO:Ag	Ethanol	Resp. time (s)	51	45	15	9
		Rec. time (s)	32	12	4	3
	Acetone	Resp. time (s)	265	189	24	7
		Rec. time (s)	59	16	5	2
	<i>n</i> -Butanol	Resp. time (s)	55	46	39	33
		Rec. time (s)	47	13	6	3
	2-Propanol	Resp. time (s)	79	56	47	18
		Rec. time (s)	48	20	5	2
	Methanol	Resp. time (s)	224	53	36	23
		Rec. time (s)	77	13	5	2
Ag(2)/ZnO:Ag	Ethanol	Resp. time (s)	40	9	19	22
		Rec. time (s)	32	29	10	10
	Acetone	Resp. time (s)	120	108	76	59
		Rec. time (s)	40	37	15	12
	<i>n</i> -Butanol	Resp. time (s)	80	28	38	28
		Rec. time (s)	44	26	23	20
	2-Propanol	Resp. time (s)	68	10	40	18
		Rec. time (s)	54	26	8	5
	Methanol	Resp. time (s)	112	30	53	86
		Rec. time (s)	65	25	10	8

Table S2. Calculated gas response and detection limit to VOCs vapors at 250 °C operating temperature for columnar films based sensor structures.

Sample	VOCs	VOC conc. (ppm)	Gas Response (I_{gas}/I_{air})	Detection limit (ppm)
ZnO:Ag	Ethanol	10	8.5 ± 1.6	0.48 ± 0.05
		50	18.6 ± 1.9	
		100	30.8 ± 3.1	
		500	89 ± 6.8	
	Acetone	10	4.9 ± 1.8	0.66 ± 0.08
		50	11.5 ± 2.1	
		100	16.5 ± 2.2	
		500	39 ± 3.6	
	n-Butanol	10	12 ± 1.2	0.22 ± 0.02
		50	29 ± 2.1	
		100	40.8 ± 3.5	
		500	98 ± 6.8	
	2-Propanol	10	15.3 ± 1.2	0.13 ± 0.01
		50	36 ± 3.1	
		100	52.5 ± 4.8	
		500	115 ± 7.1	
	Methanol	10	8.9 ± 2.1	0.06 ± 0.02
		50	23 ± 2.5	
		100	31 ± 2.6	
		500	73 ± 3.8	
Ag(1)/ZnO:Ag	Ethanol	10	19 ± 1.6	0.1 ± 0.01
		50	42 ± 2.9	
		100	74.3 ± 5.8	
		500	189 ± 10.1	
	Acetone	10	12 ± 1.5	0.17 ± 0.02
		50	32 ± 2.5	
		100	48.5 ± 3.8	
		500	112 ± 6.9	
	n-Butanol	10	15 ± 1.6	0.21 ± 0.03
		50	35 ± 2.6	
		100	66.7 ± 3.9	
		500	175 ± 5.8	
	2-Propanol	10	$25 \pm 2.$	0.05 ± 0.01
		50	51 ± 3.6	
		100	82 ± 4.8	
		500	201 ± 6.9	
	Methanol	10	8.5 ± 1.6	0.37 ± 0.05
		50	23 ± 2.1	
		100	32.3 ± 3.5	
		500	85 ± 4.8	
Ag(2)/ZnO:Ag	Ethanol	10	36 ± 2.5	0.02 ± 0.01
		50	85 ± 4.8	
		100	145 ± 9.8	
		500	355 ± 22	
	Acetone	10	23 ± 1.5	0.07 ± 0.02
		50	63 ± 3.8	
		100	100 ± 5.8	
		500	281 ± 21	
	n-Butanol	10	39 ± 1.8	0.04 ± 0.01
		50	102 ± 5.6	
		100	156 ± 6.8	
		500	405 ± 32	
	2-Propanol	10	46 ± 3.8	0.01 ± 0.005
		50	118 ± 9.8	
		100	175 ± 10.2	
		500	439 ± 23	
	Methanol	10	13 ± 1.1	0.24 ± 0.05
		50	32 ± 2.5	
		100	54 ± 3.5	
		500	145 ± 9.5	

Table S3. Calculated gas response to VOCs vapors at 250 °C operating temperature under different values of RH.

Sample	VOCs	Gas Response ($I_{\text{gas}}/I_{\text{air}}$)	
		RH 30%	RH 85%
ZnO:Ag	<i>Ethanol</i>	30.8 ± 2	16 ± 2
	<i>Acetone</i>	16.5 ± 1	8.3 ± 0.9
	<i>n-Butanol</i>	40.8 ± 2.5	22 ± 1.5
	<i>2-Propanol</i>	52.5 ± 3.5	28.3 ± 1.9
	<i>Methanol</i>	31 ± 3	15 ± 1.1
	<i>Hydrogen</i>	2.1 ± 0.5	1.3 ± 0.1
Ag(1)/ZnO:Ag	<i>Ethanol</i>	74.3 ± 5.2	53 ± 2.8
	<i>Acetone</i>	48.5 ± 4.1	39 ± 3.1
	<i>n-Butanol</i>	66.7 ± 5.2	51 ± 5
	<i>2-Propanol</i>	82 ± 6.5	63 ± 5.1
	<i>Methanol</i>	32.3 ± 1.5	26 ± 1.8
	<i>Hydrogen</i>	1.5 ± 0.1	1.4 ± 0.1
Ag(2)/ZnO:Ag	<i>Ethanol</i>	145 ± 12.5	132 ± 8.9
	<i>Acetone</i>	100 ± 8	89 ± 6.5
	<i>n-Butanol</i>	156 ± 9	143 ± 9.8
	<i>2-Propanol</i>	175 ± 10	157 ± 8.5
	<i>Methanol</i>	54 ± 2.9	50 ± 4.5
	<i>Hydrogen</i>	1.69 ± 0.1	1.6 ± 0.1

Author contributions

O. L., V. P., and A. V. synthesized the Ag-functionalized ZnO:Ag material. O. L. developed synthesis from chemical solution procedure SCS for ZnO. O. L., V. P., A. V., M.-I. T. and M. H. adapted technological approach for material synthesis and integration/fabrication of the sensors. A. V. and F. F. developed functionalization procedure, set-up and realized all experiments and XPS analysis. P. V. and O. L. carried out the measurement of sensing properties of sensors based on such structures and analyzed data. T. D. and L. K. studied TEM. V. P., O. L., M. H., R. A., M.-I. T. analyzed the results, including Raman data and revised draft. N. H.d.L., D. S.-C. and A. C. -E. realized computational part. A. V., P. V., A. C. -E., D. S.-C., R. A and O. L. drafted the article. O. L., F. F., N. H.d.L., L. K. and R. A. conceived and designed the study and approved the final version of the manuscript to be published. All authors reviewed the manuscript.

Conflicts of interest

There are no conflicts to declare.

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